

#### FEATURES

- Dual-Supply Operation . . . ±5 V to ±18 V
- Low Noise Voltage . . . 4.5 nV/√Hz
- Low Input Offset Voltage . . . 0.15 mV
- Low Total Harmonic Distortion . . . 0.002%
- High Slew Rate ... 7 V/µs
- High-Gain Bandwidth Product ... 16 MHz
- High Open-Loop AC Gain . . . 800 at 20 kHz
- Large Output-Voltage Swing . . . 14.1 V to -14.6 V
- Excellent Gain and Phase Margins

### **DESCRIPTION/ORDERING INFORMATION**

The MC33078 is a bipolar dual operational amplifier with high-performance specifications for use in quality audio and data-signal applications. This device operates over a wide range of single- and dual-supply voltages and offers low noise, high-gain bandwidth, and high slew rate. Additional features include low total harmonic distortion, excellent phase and gain margins, large output voltage swing with no deadband crossover distortion, and symmetrical sink/source performance.

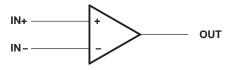
#### **ORDERING INFORMATION**

T <sub>A</sub>	PACKAGE	(1)	ORDERABLE PART NUMBER	TOP-SIDE MARKING <sup>(2)</sup>
	PDIP – P Tube of 50		MC33078P	MC33078P
–40°C to 85°C	SOIC – D	Tube of 75	MC33078D	1422070
		Reel of 2500	MC33078DR	M33078
	VSSOP/MSOP - DGK	Reel of 2500	MC33078DGKR	MN
		Reel of 250	MC33078DGKT	MY_

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

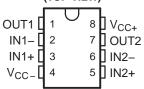
(2) DGK: The actual top-side marking has one additional character that designates the assembly/test site.

#### SYMBOL (EACH AMPLIFIER)





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



## MC33078 DUAL HIGH-SPEED LOW-NOISE OPERATIONAL AMPLIFIER

SLLS633C-OCTOBER 2004-REVISED NOVEMBER 2006

#### Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	IAX	UNIT	
V <sub>CC+</sub>	Supply voltage <sup>(2)</sup>		18	V		
V <sub>CC-</sub>	Supply voltage <sup>(2)</sup>	Supply voltage <sup>(2)</sup>				
$V_{CC+} - V_{CC-}$	Supply voltage		36	V		
	Input voltage, either input <sup>(2)(3)</sup>	V <sub>CC+</sub> or V	V <sub>CC+</sub> or V <sub>CC-</sub>			
	Input current <sup>(4)</sup>		±10			
	Duration of output short circuit <sup>(5)</sup>	ration of output short circuit <sup>(5)</sup>				
		D package		97		
$\theta_{JA}$	Package thermal impedance, junction to free $air^{(6)(7)}$	DGK package		172	°C/W	
			85			
TJ	Operating virtual junction temperature		150	°C		
T <sub>stg</sub>	Storage temperature range	-65	150	°C		

Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings (1) only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

All voltage values, except differential voltages, are with respect to the midpoint between  $V_{CC+}$  and  $V_{CC-}$ . The magnitude of the input voltage must never exceed the magnitude of the supply voltage. (2)

(3)

Excessive input current will flow if a differential input voltage in excess of approximately 0.6 V is applied between the inputs, unless (4) some limiting resistance is used.

The output may be shorted to ground or either power supply. Temperature and/or supply voltages must be limited to ensure the (5) maximum dissipation rating is not exceeded.

Maximum power dissipation is a function of  $T_{I}(max)$ ,  $\theta_{IA}$ , and  $T_{A}$ . The maximum allowable power dissipation at any allowable ambient (6) temperature is  $P_D = (T_J(max) - T_A)/\theta_{JA}$ . Operating a the absolute maximum  $T_J$  of 150°C can affect reliability. The package thermal impedance is calculated in accordance with JESD 51-7.

(7)

#### **Recommended Operating Conditions**

		MIN	MAX	UNIT
V <sub>CC</sub> -	Supply voltage	-5	-18	V
V <sub>CC+</sub>	Supply voltage	5	18	v
T <sub>A</sub>	Operating free-air temperature range	-40	85	°C

### **Electrical Characteristics**

 $V_{CC-}$  = –15 V,  $V_{CC+}$  = 15 V,  $T_A$  = 25°C (unless otherwise noted)

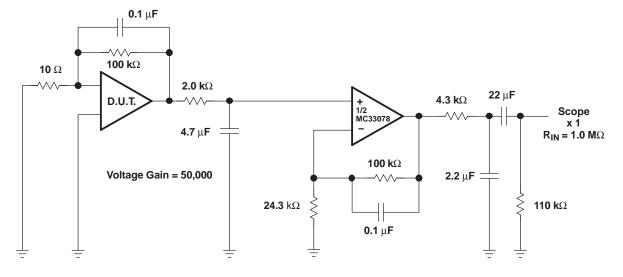
PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
V <sub>IO</sub>	Input offset voltage	$V_0 = 0, R_s =$	$= 10 \ \Omega, \ V_{CM} = 0$	$T_{A} = 25^{\circ}C$ $T_{A} = -40^{\circ}C \text{ to } 85^{\circ}C$		0.15	2	mV
$\alpha V_{IO}$	Input offset voltage temperature coefficient	$V_{0} = 0, R_{S} =$	$= 10 \ \Omega, \ V_{CM} = 0$	$T_A = -40^{\circ}C$ to $85^{\circ}C$		2		μV/°C
I <sub>IB</sub>	Input bias current	$V_{O} = 0, V_{CM}$	= 0	$T_{A} = 25^{\circ}C$ $T_{A} = -40^{\circ}C \text{ to } 85^{\circ}C$		300	750 800	nA
I <sub>IO</sub>	Input offset current	$V_{O} = 0, V_{CM}$	= 0	$T_{A} = 25^{\circ}C$ $T_{A} = -40^{\circ}C \text{ to } 85^{\circ}C$		25	150 175	nA
V <sub>ICR</sub>	Common-mode input voltage range	$\Delta V_{IO} = 5 \text{ mV},$	V <sub>O</sub> = 0		±13	±14		V
A <sub>VD</sub>	Large-signal differential voltage amplification	$R_L \ge 2 k\Omega, V_O$	= ±10 V	$T_{A} = 25^{\circ}C$ $T_{A} = -40^{\circ}C \text{ to } 85^{\circ}C$	90 85	110		dB
		$V_{ID} = \pm 1 V$	R <sub>L</sub> = 600 Ω	V <sub>OM+</sub> V <sub>OM-</sub>		10.7 -11.9		
V <sub>OM</sub>	Maximum output voltage swing		$R_{L} = 2k \ \Omega$	V <sub>OM+</sub> V <sub>OM-</sub>	13.2 -13.2	13.8 -13.7		V
			$R_L = 10k \Omega$	V <sub>OM+</sub> V <sub>OM-</sub>	13.5 -14	14.1 –14.6		
CMMR	Common-mode rejection ratio	V <sub>IN</sub> = ±13 V				100		dB
k <sub>SVR</sub> <sup>(1)</sup>	Supply-voltage rejection ratio	$V_{CC+} = 5 V \text{ to } 15 V, V_{CC-} = -5 V \text{ to } -15 V$				105		dB
I <sub>OS</sub>	Output short-circuit current	V <sub>ID</sub>   = 1 V, Ou		Source current Sink current	15 20	29 -37		mA
I <sub>CC</sub>	Supply current (per channel)	V <sub>O</sub> = 0		$T_{A} = 25^{\circ}C$ $T_{A} = -40^{\circ}C \text{ to } 85^{\circ}C$		2.05	2.5 2.75	mA

(1) Measured with  $V_{CC\pm}$  differentially varied at the same time

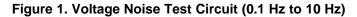
#### **Operating Characteristics**

 $V_{CC-}$  = –15 V,  $V_{CC+}$  = 15 V,  $T_A$  = 25°C (unless otherwise noted)

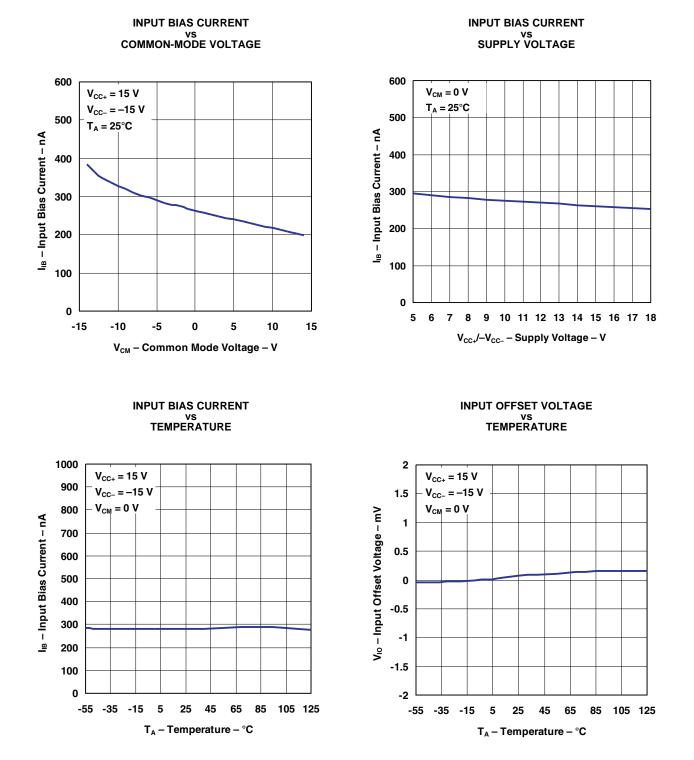
PARAMETER		TES	TEST CONDITIONS			MAX	UNIT
SR	Slew rate at unity gain	$A_{VD} = 1, V_{IN} = -10 V t$	to 10 V, $R_L = 2 k\Omega$ , $C_L = 100 pF$	5	7		V/µs
GBW	Gain bandwidth product	f = 100 kHz		10	16		MHz
B <sub>1</sub>	Unity gain frequency	Open loop			9		MHz
<u>^</u>			C <sub>L</sub> = 0 pF		-11		
G <sub>m</sub>	Gain margin	$R_{L} = 2 k\Omega$ $C_{L} = 100 \text{ pF}$		-6		dB	
æ		D 010	C <sub>L</sub> = 0 pF		55		
$\Phi_{\sf m}$	Phase margin	$R_L = 2 k\Omega$	C <sub>L</sub> = 100 pF		40		deg
	Amp-to-amp isolation	f = 20 Hz to 20 kHz	f = 20 Hz to 20 kHz				dB
	Power bandwidth	V <sub>O</sub> = 27 V <sub>(PP)</sub> , R <sub>L</sub> = 2	$V_{O} = 27 V_{(PP)}, R_{L} = 2 k\Omega, THD \le 1\%$				kHz
THD	Total harmonic distortion	$V_{O} = 3 V_{rms}, A_{VD} = 1,$	$R_L = 2 k\Omega$ , f = 20 Hz to 20 kHz		0.002		%
Z <sub>o</sub>	Open-loop output impedance	V <sub>O</sub> = 0, f = 9 MHz	V <sub>O</sub> = 0, f = 9 MHz				Ω
r <sub>id</sub>	Differential input resistance	$V_{CM} = 0$		175		kΩ	
C <sub>id</sub>	Differential input capacitance	$V_{CM} = 0$		12		pF	
V <sub>n</sub>	Equivalent input noise voltage	f = 1 kHz, R <sub>S</sub> = 100 Ω		4.5		nV/√ <del>Hz</del>	
I <sub>n</sub>	Equivalent input noise current	f = 1 kHz		0.5		pA/√ <del>Hz</del>	



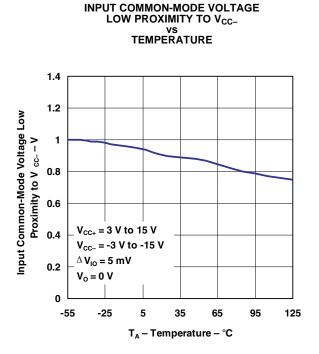
NOTE: All capacitors are non-polarized.

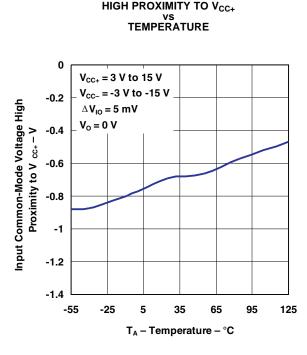


#### **TYPICAL CHARACTERISTICS**



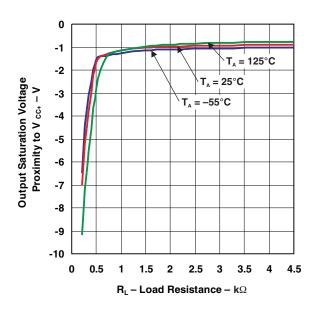




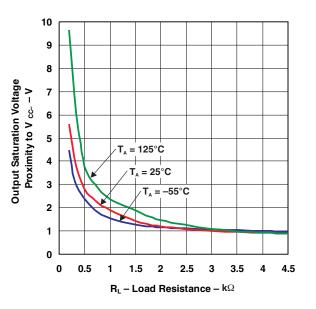


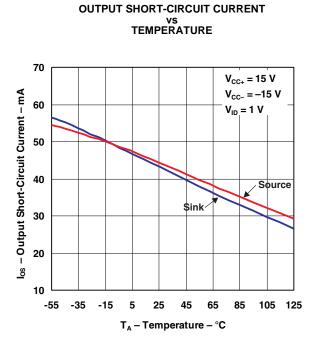
INPUT COMMON-MODE VOLTAGE

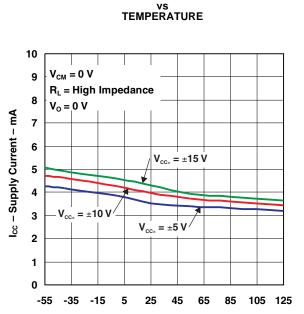
#### OUTPUT SATURATION VOLTAGE PROXIMITY TO V<sub>CC+</sub> vs LOAD RESISTANCE



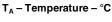
#### OUTPUT SATURATION VOLTAGE PROXIMITY TO V<sub>CC-</sub> vs LOAD RESISTANCE





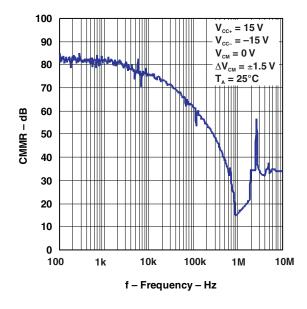


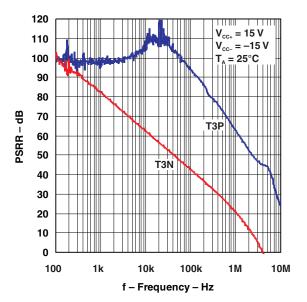
SUPPLY CURRENT









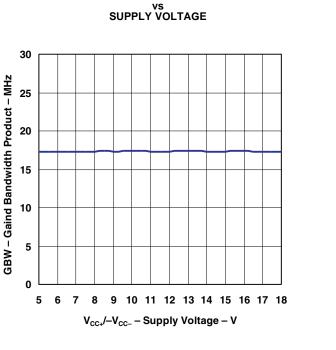


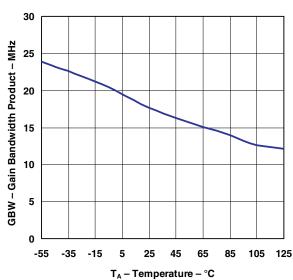
## **TYPICAL CHARACTERISTICS (continued)**

GAIN BANDWIDTH PRODUCT



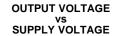
#### **TYPICAL CHARACTERISTICS (continued)**

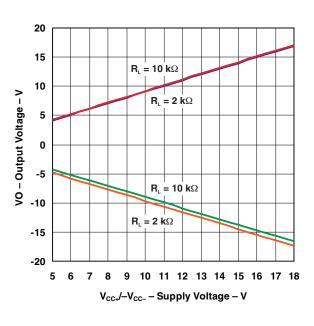




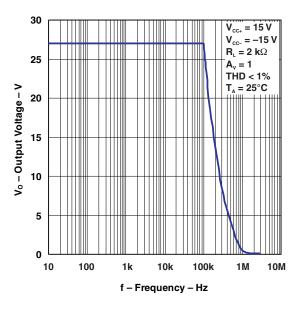
GAIN BANDWIDTH PRODUCT

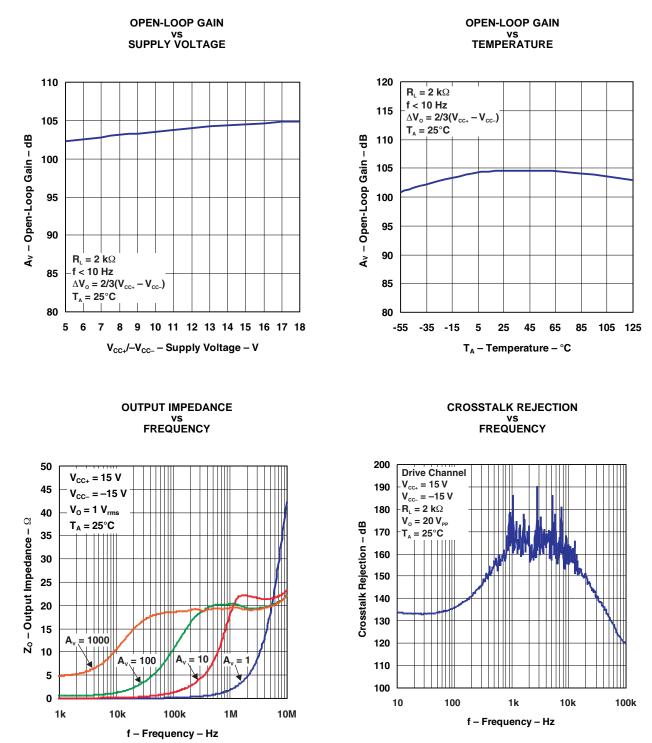
vs TEMPERATURE



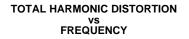












10k

1

0.1

0.01

0.001

0.0001

10

THD – Total Harmonic Distortion – %

V<sub>cc+</sub> = 15 V

 $V_{cc-} = -15 V$ 

 $V_o = 1 V_{rms}$ 

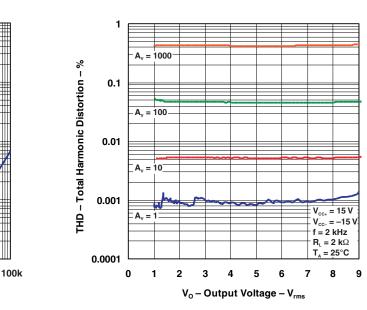
**R**<sub>L</sub> = 2 kΩ

T<sub>A</sub> = 25°C

100

 $A_{v} = 1$ 

TOTAL HARMONIC DISTORTION VS OUTPUT VOLTAGE

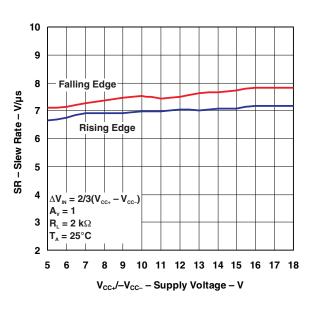


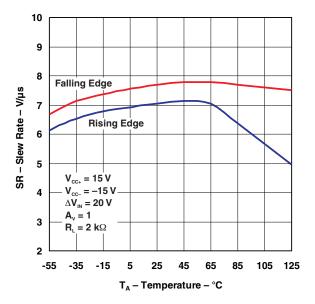


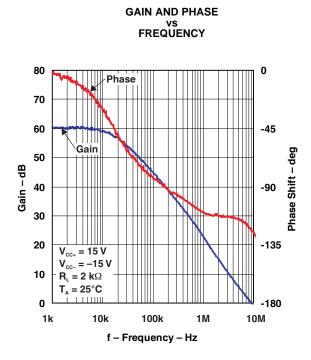
1k

f - Frequency - Hz

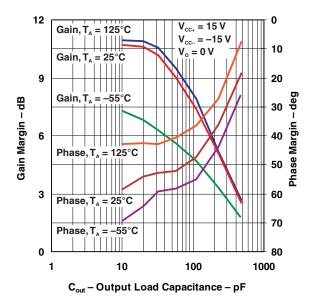




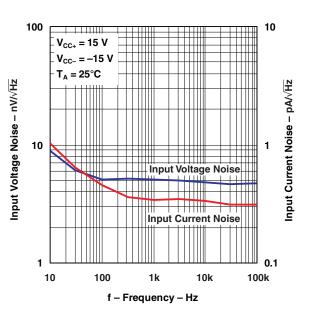




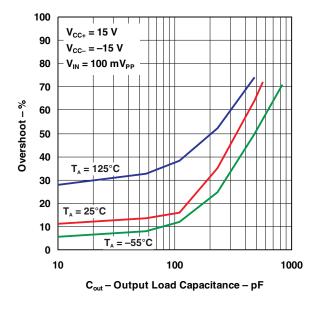
GAIN AND PHASE MARGIN VS OUTPUT LOAD CAPACITANCE



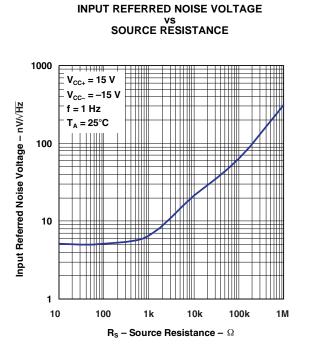
INPUT VOLTAGE AND CURRENT NOISE vs FREQUENCY

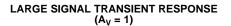


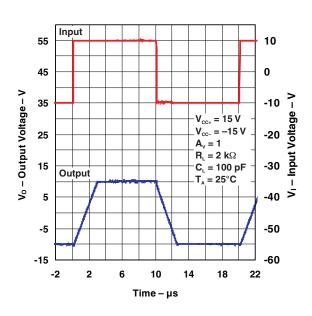
OVERSHOOT vs OUTPUT LOAD CAPACITANCE

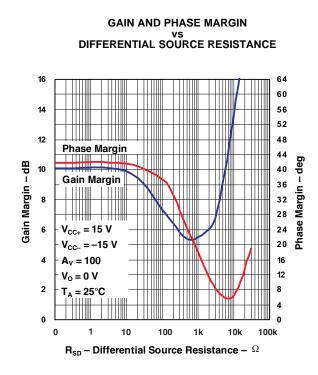


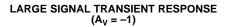


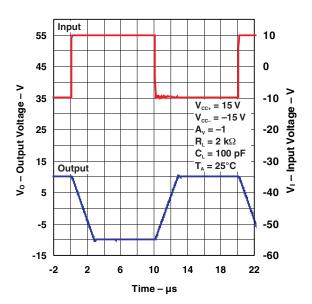








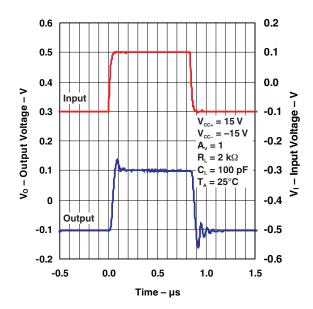


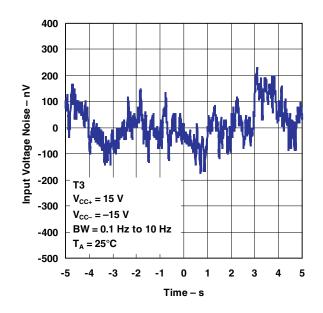




#### SMALL SIGNAL TRANSIENT RESPONSE

LOW\_FREQUENCY NOISE







#### **APPLICATION INFORMATION**

#### **Output Characteristics**

All operating characteristics are specified with 100-pF load capacitance. The MC33078 can drive higher capacitance loads. However, as the load capacitance increases, the resulting response pole occurs at lower frequencies, causing ringing, peaking, or oscillation. The value of the load capacitance at which oscillation occurs varies from lot to lot. If an application appears to be sensitive to oscillation due to load capacitance, adding a small resistance in series with the load should alleviate the problem (see Figure 2).

PULSE RESPONSE

 $(R_L = 2 k\Omega, C_L = 560 pF)$ 

# PULSE RESPONSE ( $R_L = 600 \Omega$ , $C_L = 380 pF$ )



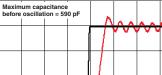


PULSE RESPONSE

 $(R_0 = 4 \Omega, C_0 = 1000 \text{ pF}, R_L = 2 \text{ k}\Omega)$ 

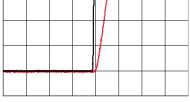


0.25 V per Division



PULSE RESPONSE

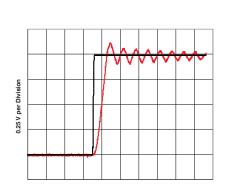
 $(R_L = 10 \text{ k}\Omega, C_L = 590 \text{ pF})$ 



250 ns per Division

PULSE RESPONSE ( $R_0 = 0 \ \Omega$ ,  $C_0 = 1000 \ pF$ ,  $R_L = 2 \ k\Omega$ )

250 ns per Division



250 ns per Division

PULSE RESPONSE (R<sub>0</sub> = 35  $\Omega$ , C<sub>0</sub> = 1000 pF, R<sub>L</sub> = 2 k $\Omega$ )



250 ns per Division

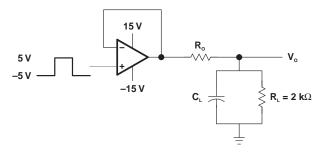


Figure 2. Output Characteristics

0.25 V per Division

#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
MC33078D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MC33078DE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MC33078DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MC33078DGKR	ACTIVE	MSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MC33078DGKRG4	ACTIVE	MSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MC33078DGKT	ACTIVE	MSOP	DGK	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MC33078DGKTG4	ACTIVE	MSOP	DGK	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MC33078DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MC33078DRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MC33078DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MC33078P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
MC33078PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

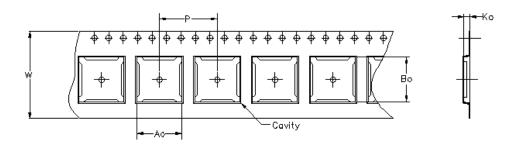
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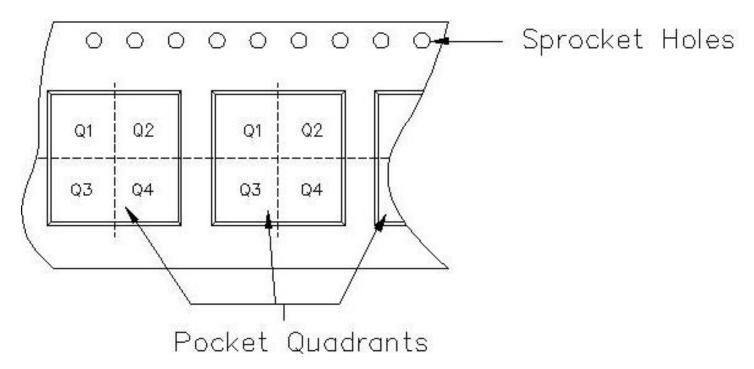


16-Jul-2007



Carrier tape design is defined largely by the component lentgh, width, and thickness.

Ao = Dimension designed to accommodate the component width.							
Bo = Dimension designed to accommodate the component length.							
Ko = Dimension designed to accommodate the component thickness.							
W = Overall width of the carrier tape.							
P = Pitch between successive cavity centers.							



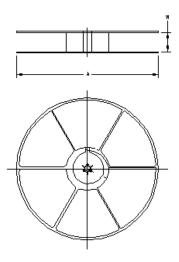
TAPE AND REEL INFORMATION

# PACKAGE MATERIALS INFORMATION



16-Jul-2007

Device	Package	Pins	Site	Reel Diameter (mm)	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MC33078DGKR	DGK	8	NSE	330	12	5.3	3.3	1.3	8	12	Q1
MC33078DGKT	DGK	8	NSE	180	12	5.3	3.3	1.3	8	12	Q1
MC33078DR	D	8	FMX	330	12	6.4	5.2	2.1	8	12	Q1
MC33078DR	D	8	MLA	330	12	6.4	5.2	2.1	8	12	Q1



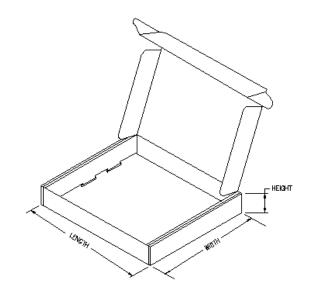
## TAPE AND REEL BOX INFORMATION

Device	Package	Pins	Site	Length (mm)	Width (mm)	Height (mm)
MC33078DGKR	DGK	8	NSE	370.0	355.0	55.0
MC33078DGKT	DGK	8	NSE	220.0	205.0	50.0
MC33078DR	D	8	FMX	342.9	336.6	20.64
MC33078DR	D	8	MLA	346.0	346.0	29.0



## PACKAGE MATERIALS INFORMATION

16-Jul-2007



## **MECHANICAL DATA**

MPDI001A - JANUARY 1995 - REVISED JUNE 1999



- NOTES: A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Falls within JEDEC MS-001

For the latest package information, go to http://www.ti.com/sc/docs/package/pkg\_info.htm



DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.

- D Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



D (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.

Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.

E. Reference JEDEC MS-012 variation AA.



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